

Form PTO-1449  INFORMATION DISCLOSURE CITATION IN AN APPLICATION  (Use several sheets if necessary)				Document Number (Spec/no.) <b>INT-03-014</b>	Application Number <b>10/827,061</b>		
				Applicant <b>Thomas Arsenbrey</b>			
				Filing Date <b>04/19/04</b>	Drawn At Date <b>28/21</b>		
<b>U. S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILED DATE IF APPROPRIATE	
2004 CT MARKED PARKER	611113438/29/00		Unami et al.	310	366	8/20/98	
CT	42674805/12/81		Kanematsu et al.	310	366	5/23/79	
CT	4786837/11/22/88		Kalnin et al.	310	364	5/5/87	
CT	6664863/12/16/03		Okamoto et al.	331	117 R	7/24/00	
CT	62687787/31/01		Mucke et al.	331	117 R	5/3/99	
<b>FOREIGN PATENT DOCUMENTS</b>							
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO	
CT	GB 2377449A	1/15/03	United Kingdom	208K	3/08		
<b>OTHER DOCUMENTS</b> (Including Author, Title, Date, Page, Etc.)							
CT -	Cleland et al., "Fabrication of high frequency nanometer scale mechanical resonators from bulk Si crystals", Applied Physics Letter 69(18), 28 Oct. 1996, pp. 2653-2655.						
CT							
EXAMINER	/Chuc Tran/			DATE CONSIDERED 08/17/2006			

**EXAMINER:** Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.